

## Preferential gallium for zinc cation exchange in $\text{In}_x\text{Zn}_y\text{P}$ nanocrystals

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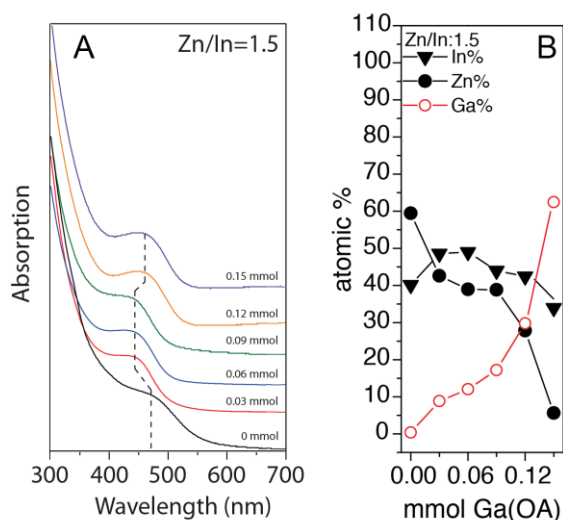
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InP based nanocrystals (NCs) are a promising low-toxicity alternative to cadmium-based NCs for light emitting applications. However, achieving near-unity photoluminescent quantum yields (PL QYs) and high photostability has proved a challenge for InP NCs. Some progress has been made by adding  $\text{Zn}^{2+}$  salts to the synthesis of InP NCs, which we have shown results in the formation of  $\text{In}_x\text{Zn}_y\text{P}$  nanocrystals and an improvement of their PL QY from < 1% (InP) to around 15% (InZnP) [1]. Further improvements in PL up to 50% have been reported by Kim et al. [2] by the addition of  $\text{Ga}^{3+}$  salts to  $\text{In}_x\text{Zn}_y\text{P}$  NCs, which they attribute to the growth of a GaP shell *via* a cation exchange between  $\text{Ga}^{3+}$  and  $\text{In}^{3+}$ .

In this presentation we will argue that the PL enhancement afforded by  $\text{Ga}^{3+}$  is actually the result of a preferential cation exchange between  $\text{Ga}^{3+}$  and  $\text{Zn}^{2+}$ . This is based on the combination of optical spectroscopy, compositional analysis (ICP-AES) and electron microscopy to characterise the reaction between  $\text{Ga}^{3+}$  and  $\text{In}_x\text{Zn}_y\text{P}$  NCs as a function of added  $\text{Ga}^{3+}$  (Figure 1). The results show a strong dependence on the zinc content in the starting nanocrystals, and suggest the gradual formation of a highly luminescent  $\text{In}_x\text{Zn}_y\text{P}/\text{In}_a\text{Ga}_b\text{P}$  core-shell structure *via* cation exchange. Finally, we will demonstrate the PL QY can be further increased up to 75% by further growth of an outer lattice-matched  $\text{ZnSe}_z\text{S}_{1-z}$  shell, which also results in prolonged stability under UV illumination at ambient conditions. [3]



**Fig. 1** (A) Absorbance of  $\text{InZnP}$  nanocrystals ( $\text{Zn}/\text{In} = 1.5$ , 0.12 mmol indium feed) as gallium oleate is added. Traces are offset with increasing gallium oleate addition. (B) Relative atomic percent of In, Zn and Ga for the same samples measured using ICP.

1) Pietra, F.; de Trizio, L. et al. *ACS Nano* **2016**, *10*, 4754–62.

2) Kim, S.; Kim, T.; et al. *Journal of the American Chemical Society* **2012**, *134*, 3804–3809.

3) Pietra, F.; Kirkwood, N.; de Trizio, L. et al. *Manuscript in preparation*, **2017**.